

# **Absolute Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	$V_{CBO}$	50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	45	V
Emitter-Base Voltage	V <sub>EBO</sub>	6.0	V
Collector Current	Ic	100	mA

# Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	$R_{\theta JA}$	833	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

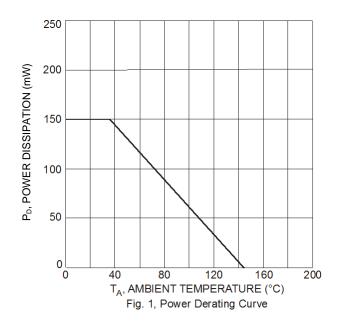
### ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes:

- 5. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

## **Thermal Characteristics and Derating Information**





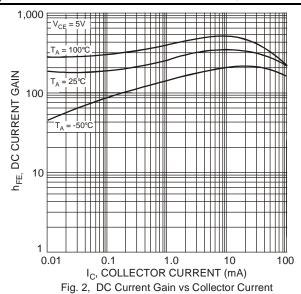
# **Electrical Characteristics** (@ $T_A = \pm 25$ °C, unless otherwise specified.)

Characteristic		Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)		-					
Collector-Base Breakdown Voltage		$BV_{CBO}$	50	_		V	$I_C = 10\mu A, I_E = 0$
Collector-Emitter Breakdown Voltage	Collector-Emitter Breakdown Voltage		45	_	_	V	$I_C = 1 \text{mA}, I_B = 0$
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	6.0	_	_	V	$I_E = 10\mu A, I_C = 0$
ON CHARACTERISTICS (Note 7)							
DC Current Gain	Current Gain A B C	h <sub>FE</sub>	110 200 420	— 290 520	220 450 800	_	$V_{CE} = 5.0V, I_{C} = 2.0mA$
Collector-Emitter Saturation Voltage		V <sub>CE(SAT)</sub>		_	250 600	mV	$I_C = 10mA, I_B = 0.5mA$ $I_C = 100mA, I_B = 5mA$
Base-Emitter Saturation Voltage		V <sub>BE(SAT)</sub>		700 900	_	mV	$I_C = 10mA, I_B = 0.5mA$ $I_C = 100mA, I_B = 5mA$
Base-Emitter Voltage		V <sub>BE</sub>	580 —	660 —	700 770	mV	$V_{CE} = 5.0V, I_{C} = 2.0mA$ $V_{CE} = 5.0V, I_{C} = 10mA$
Collector-Emitter Cutoff Current		I <sub>CBO</sub>	ı		15 5.0	nΑ μΑ	V <sub>CB</sub> = 30V V <sub>CB</sub> = 30V, T <sub>A</sub> = +150°C
SMALL SIGNAL CHARACTERISTICS							
Output Capacitance		C <sub>OBO</sub>	_	_	4.5	pF	$V_{CB} = 10V, f = 1.0MHz$
Current Gain-Bandwidth Product		f⊤	100	_	_	MHz	V <sub>CE</sub> = 5V, I <sub>C</sub> = 10mA, f = 100MHz
Noise Figure	BC847BT BC847CT	NF		_	1.0 4.0	dB	$V_{CE} = 5V$ , $R_S = 2k\Omega$ , $f = 1MHz$ , $BW = 200Hz$

Note: 7. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



### Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



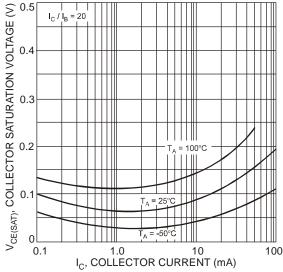


Fig. 3, Collector Saturation Voltage vs Collector Current

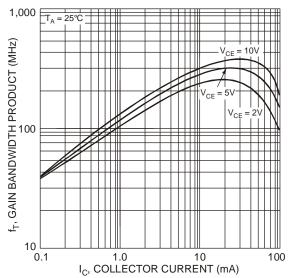


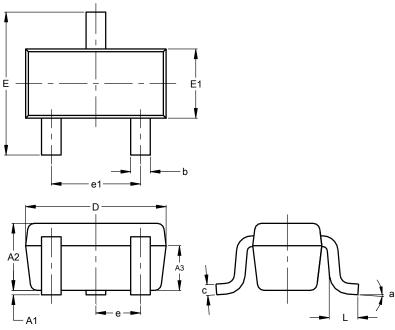
Fig. 4, Gain Bandwidth Product vs Collector Current



### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT523

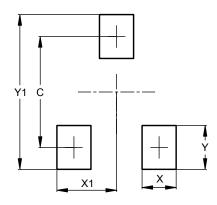


SOT523					
Dim	Min	Max	Тур		
Α	0.60	0.80	0.75		
A1	0.00	0.10	0.05		
A3	0.45	0.65	0.50		
b	0.15	0.30	0.22		
С	0.10	0.20	0.12		
D	1.50	1.70	1.60		
Е	1.45	1.75	1.60		
E1	0.75	0.85	0.80		
е	e 0.50 BSC				
e1	0.90	1.10	1.00		
L	0.20	0.40	0.33		
а	0°		8°		
All Dimensions in mm					

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### SOT523



Dimensions	Value
С	1.29
Х	0.40
X1	0.70
Υ	0.51
Y1	1.80



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